

SN74LV4T125 Single Power Supply Quadruple Buffer Translator GATE With 3-State Output CMOS Logic Level Shifter

1 Features

- Single-Supply Voltage Translator at 5.0-V, 3.3-V, 2.5-V, and 1.8-V V_{CC}
- Operating Range of 1.8 V to 5.5 V
- Up Translation
 - 1.2 V⁽¹⁾ to 1.8 V at 1.8-V V_{CC}
 - 1.5 V⁽¹⁾ to 2.5 V at 2.5-V V_{CC}
 - 1.8 V⁽¹⁾ to 3.3 V at 3.3-V V_{CC}
 - 3.3 V to 5.0 V at 5.0-V V_{CC}
- Down Translation
 - 3.3 V to 1.8 V at 1.8-V V_{CC}
 - 3.3 V to 2.5 V at 2.5-V V_{CC}
 - 5.0 V to 3.3 V at 3.3-V V_{CC}
- Logic Output is Referenced to V_{CC}
- Characterized up to 50 MHz at 3.3-V V_{CC}
- 5.5 V Tolerance on Input Pins
- –40°C to 125°C Operating Temperature Range
- Pb-Free Packages Available: SC-70 (RGY)
 - 3.5 × 3.5 × 1 mm
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Supports Standard Logic Pinouts
- I_{off} Support Partial-Power-Down Mode Operation
- CMOS Output B Compatible with AUP125, LVC125 ¹

2 Applications

- Tablet
- Smartphone
- Personal Computer
- Industrial Automotive

3 Description

SN74LV4T125 is a low-voltage CMOS buffer gate that operates at a wider voltage range for portable, telecom, industrial, and automotive applications. The output level is referenced to the supply voltage and is able to support 1.8-V, 2.5-V, 3.3-V, and 5-V CMOS levels.

The input is designed with a lower threshold circuit to match 1.8-V input logic at $V_{CC} = 3.3$ V and can be used in 1.8 V to 3.3 V level-up translation. In addition, the 5-V tolerant input pins enable down translation (for example, 3.3 V to 2.5 V output at $V_{CC} = 2.5$ V). The wide V_{CC} range of 1.8 V to 5.5 V allows the generation of desired output levels to connect to controllers or processors.

The SN74LV4T125 device is designed with current-drive capability of 8 mA to reduce line reflections, overshoot, and undershoot caused by high-drive outputs.

Device Information

PART NUMBER ⁽¹⁾	PACKAGE	BODY SIZE (NOM)
SN74LV4T125	PW (TSSOP, 14)	5.00 mm x 4.40 mm
	RGY (VQFN, 14)	3.50 mm x 3.50 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

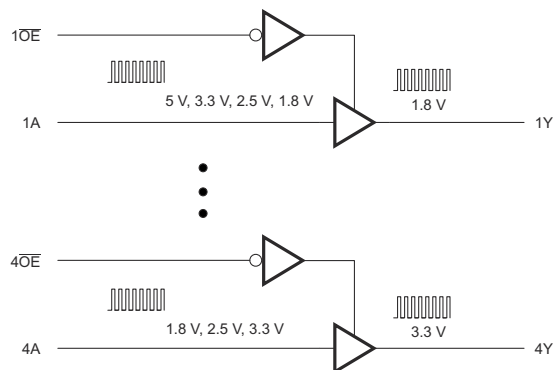


Figure 3-1. Simplified Application Diagram

¹ Refer the V_{IH}/V_{IL} and output drive for lower V_{CC} condition.



Table of Contents

1 Features	1	8.2 Functional Block Diagram.....	10
2 Applications	1	8.3 Feature Description.....	10
3 Description	1	8.4 Device Functional Modes.....	11
4 Revision History	2	9 Applications and Implementation	12
5 Pin Configuration and Functions	3	9.1 Application Information.....	12
Pin Functions.....	3	9.2 Typical Application.....	12
6 Specifications	4	10 Power Supply Recommendations	13
6.1 Absolute Maximum Ratings.....	4	11 Layout	14
6.2 ESD Ratings.....	4	11.1 Layout Guidelines.....	14
6.3 Recommended Operating Conditions.....	5	11.2 Layout Example.....	14
6.4 Thermal Information.....	5	12 Device and Documentation Support	15
6.5 Electrical Characteristics.....	6	12.1 Documentation Support.....	15
6.6 Switching Characteristics.....	7	12.2 Receiving Notification of Documentation Updates..	15
6.7 Noise Characteristics.....	8	12.3 Support Resources.....	15
6.8 Operating Characteristics.....	8	12.4 Trademarks.....	15
6.9 Typical Characteristics.....	8	12.5 Electrostatic Discharge Caution.....	15
7 Parameter Measurement Information	9	12.6 Glossary.....	15
8 Detailed Description	10	13 Mechanical, Packaging, and Orderable Information	15
8.1 Overview.....	10		

4 Revision History

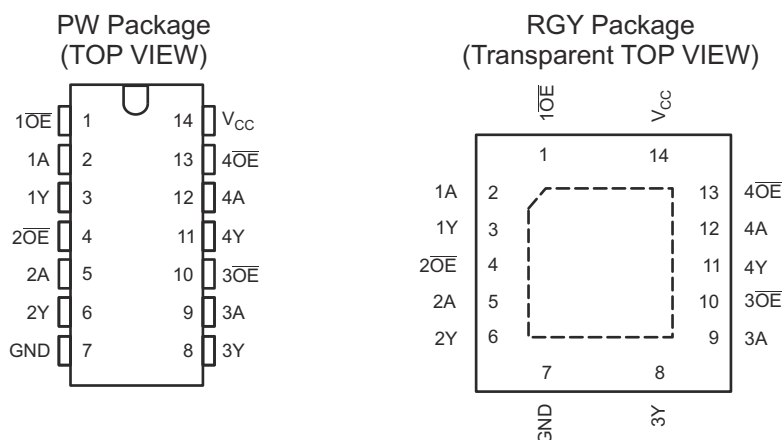
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (March 2014) to Revision C (June 2022)	Page
• I _{off} Support Partial-Power-Down Mode Operation to Features.....	1
• Updated the numbering format for tables, figures, and cross-references throughout the document.....	1
• Added ESD Ratings table, Receiving Notification of Documentation Updates section, and Support Resources section.....	1

Changes from Revision A (March 2014) to Revision B (September 2014)	Page
• Updated Features.	1
• Updated Pin Functions table.	3
• Added ESD Ratings table, Thermal Information table, Typical Characteristics section, Pin Configuration and Functions section, Detailed Description section, Power Supply Recommendations section, Layout section, Receiving Notification of Documentation Updates section, and Community Resources section.....	4
• Updated Detailed Design Procedure section.	13

Changes from Revision * (February 2014) to Revision A (March 2014)	Page
• Updated 1 page preview document to full version.	1

5 Pin Configuration and Functions



Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NO.	NAME		
1	1 \overline{OE}	I	Enable 1
2	1A	I	Input 1
3	1Y	O	Output 1
4	2 \overline{OE}	I	Enable 2
5	2A	I	Input 2
6	2Y	O	Output 2
7	GND	—	Ground Pin
8	3Y	O	Output 3
9	3A	I	Input 3
10	3 \overline{OE}	I	Enable 3
11	4Y	O	Output 4
12	4A	I	Input 4
13	4 \overline{OE}	I	Enable 4
14	V _{CC}	—	Power Pin

(1) I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		−0.5	7.0	V
V _I	Input voltage range ⁽²⁾		−0.5	7.0	V
V _O	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾		−0.5	4.6	V
	Voltage range applied to any output in the high or low state ⁽²⁾		−0.5	V _{CC} + 0.5	
I _{IK}	Input clamp current	V _I < 0	−20		mA
I _{OK}	Output clamp current	V _O < 0 or V _O > V _{CC}	±50		mA
I _O	Continuous output current		±35		mA
	Continuous current through V _{CC} or GND		±70		mA
T _J	Junction temperature		150		°C
T _{stg}	Storage temperature		−65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

6.2 ESD Ratings

		VALUE	UNIT	
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
		Machine Model (MM), per JEDEC specification	±200	
		Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002 ⁽²⁾	±1000	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		1.6	5.5	V
V _I	Input voltage		0	5.5	V
V _O	Output voltage	High or Low State	0	V _{CC}	V
		H-Z	0	V _{CC}	V
I _{OH}	High-level output current	V _{CC} = 1.8 V		–3	mA
		V _{CC} = 2.5 V		–5	
		V _{CC} = 3.3 V		–8	
		V _{CC} = 5.0 V		–16	
I _{OL}	Low-level output current	V _{CC} = 1.8 V		3	mA
		V _{CC} = 2.5 V		5	
		V _{CC} = 3.3 V		8	
		V _{CC} = 5.0 V		16	
Δt/Δv	Input transition rise or fall rate	V _{CC} = 1.6 V to 2.0 V		20	ns/V
		V _{CC} = 2.3 V to 2.7 V		20	
		V _{CC} = 3 V or 3.6 V		20	
		V _{CC} = 4.5 V to 5.0 V		20	
T _A	Operating free-air temperature		–40	125	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number [SCBA004](#).

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		SN74LV4T125		UNIT
		PW	RGY	
		14 PINS	14 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	126.9	52.9	°C/W
R _{θJCTop}	Junction-to-case (top) thermal resistance	54.2	67.8	
R _{θJB}	Junction-to-board thermal resistance	68.6	29.0	
ψ _{JT}	Junction-to-top characterization parameter	7.5	2.6	
ψ _{JB}	Junction-to-board characterization parameter	68.0	29.1	
R _{θJCbott}	Junction-to-case (bottom) thermal resistance	—	9.3	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report ([SPRA953](#)).

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CC}	T _A = 25°C			T _A = –40°C to 125°C		UNIT
				MIN	TYP	MAX	MIN	MAX	
V _{IH}	High-level input voltage		V _{CC} = 1.65 V to 1.9 V	0.95			1		V
			V _{CC} = 2.3 V to 2.7 V	1.1			1.2		
			V _{CC} = 3 V to 3.6 V	1.3			1.35		
			V _{CC} = 4.5 V to 5.0 V	2			2		
V _{IL}	Low-level input voltage		V _{CC} = 1.65 V to 1.9 V	0.55			0.5		V
			V _{CC} = 2.3 V to 2.77 V	0.7			0.6		
			V _{CC} = 3 V to 3.6 V	0.85			0.75		
			V _{CC} = 4.5 V to 5.5 V	0.9			0.85		
V _{OH}	High-level output voltage	I _{OH} = –50 μA	V _{CC} = 1.65 V to 5.5 V	V _{CC} – 0.1			V _{CC} – 0.1		V
		I _{OH} = –2 mA	V _{CC} = 1.65 V	1.4			1.35		V
		I _{OH} = –3 mA	V _{CC} = 2.3 V	2.05			2.0		V
		I _{OH} = –5 mA	V _{CC} = 3.0 V	2.7			2.6		V
		I _{OH} = –8 mA		2.6			2.5		
		I _{OH} = –8 mA	V _{CC} = 4.5 V	3.7			3.6		V
		I _{OH} = –16 mA		3.8			3.7		
		I _{OH} = –16 mA	V _{CC} = 5.0 V	4.4			4.3		V
V _{OL}	Low-level output voltage	I _{OL} = 50 μA	V _{CC} = 1.65 V to 5.5 V	0.1			0.1		V
		I _{OH} = 2 mA	V _{CC} = 1.65 V	0.1			0.1		V
			V _{CC} = 1.8 V	0.2			0.3		
		I _{OH} = 3 mA	V _{CC} = 2.3 V	0.2			0.3		V
			V _{CC} = 2.5 V	0.25			0.3		
		I _{OH} = 5 mA	V _{CC} = 3.0 V	0.35			0.4		V
		I _{OH} = 8 mA		0.4			0.45		
		I _{OH} = 8 mA	V _{CC} = 3.3 V	0.45			0.5		V
		I _{OH} = 8 mA	V _{CC} = 4.5 V	0.50			0.55		V
		I _{OH} = 16 mA		0.55			0.55		
I _{OH} = 16 mA	V _{CC} = 5.0 V	0.55			0.55		V		
I _I	Input leakage current	V _I = 0 V or V _{CC}	V _{CC} = 0 V, 1.8 V, 2.5 V, 3.3 V, 5.5 V	±0.1			±1		μA
I _{CC}	Static supply current	V _I = 0 V or V _{CC} , I _O = 0; open on loading	V _{CC} = 5.0 V	2			20		μA
			V _{CC} = 3.3 V	2			20		
			V _{CC} = 2.5 V	2			20		
			V _{CC} = 1.8 V	2			20		
ΔI _{CC}	Additional static supply current	One input at 0.3 V or 3.4 V Other inputs at 0 or V _{CC} , I _O = 0	V _{CC} = 5.5 V	1.35			1.5		μA
		One input at 0.3 V or 1.1 V Other inputs at 0 or V _{CC} , I _O = 0	V _{CC} = 1.8 V						
I _{OZ}	Off-state (High Impedance State) Output Current	V _O = V _{CC} or GND	V _{CC} = 5.5 V	±0.25			±2.5		μA
I _{off}	Partial power down current	V _O or V _I = 0 to 5.5 V	V _{CC} = 0 V	0.5			5		μA
C _i	Input capacitance	V _I = V _{CC} or GND	V _{CC} = 3.3 V	1.6			1.6		pF
C _o	Output capacitance	V _O = V _{CC} or GND	V _{CC} = 3.3 V	4.8			4.8		pF

6.6 Switching Characteristics

over operating free-air temperature range (unless otherwise noted) (see [Figure 7-1](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	FREQUENCY (TYP)	V _{CC}	C _L	T _A = 25°C			T _A = –65°C to 125°C			UNIT
						MIN	TYP	MAX	MIN	TYP	MAX	
t _{pd}	Any In	Y	DC to 50 MHz	5.0 V	15 pF		2.8	3.2		3	3.5	ns
					30 pF		3	3.5		3	4.5	
				3.3 V	15 pF		4	4.5		5	5.5	
					30 pF		5	5.5		5.5	6.5	
			DC to 50 MHz	2.5 V	15 pF		5.5	6.5		7	7.5	ns
					30 pF		6.5	7		7.5	8.5	
t _{pZH}	\overline{OE}	Y	DC to 50 MHz	5.0 V	15 pF		3.5	4		3.5	4	ns
					30 pF		3.8	4.2		4	4.5	
				3.3 V	15 pF		5	5.8		5.8	6.1	
					30 pF		5.5	6		5.7	6.5	
			DC to 50 MHz	2.5 V	15 pF		7.5	8		8.5	9	ns
					30 pF		8	8.5		9	9.5	
t _{pZL}	\overline{OE}	Y	DC to 50 MHz	5.0 V	15 pF		3	3.5		3.5	4	ns
					30 pF		3.5	4		4	4.5	
				3.3 V	15 pF		5.3	5.6		6	6.2	
					30 pF		5.8	6.2		7	7.5	
			DC to 50 MHz	2.5 V	15 pF		8	8.5		9	9.5	ns
					30 pF		9	9.5		10.5	11	
t _{PHZ}	\overline{OE}	Y	DC to 50 MHz	5.0 V	15 pF		3	3.5		3.5	4	ns
					30 pF		3.5	4		4	4.5	
				3.3 V	15 pF		3.5	4		4.5	5	
					30 pF		5	6		6.5	7	
			DC to 50 MHz	2.5 V	15 pF		5.5	6		6	6.5	ns
					30 pF		7.5	8		8	9	
t _{PLZ}	\overline{OE}	Y	DC to 50 MHz	5.0 V	15 pF		2	2.5		2	2.7	ns
					30 pF		2	3		2	3.2	
				3.3 V	15 pF		2.3	2.8		2.5	3.2	
					30 pF		2.8	3.2		3.3	4	
			DC to 50 MHz	2.5 V	15 pF		3.3	3.8		3.8	4.2	ns
					30 pF		4	4.3		4.2	5	
t _{sk}	Any In	Y	DC to 50 MHz	5.0 V to 2.5 V	15 pF					1		ns
			DC to 30 MHz	1.8 V	15 pF							

6.7 Noise Characteristics

$V_{CC} = 3.3\text{ V}$, $C_L = 50\text{ pF}$, $T_A = 25^\circ\text{C}$ ⁽¹⁾

PARAMETER		MIN	TYP	MAX	UNIT
$V_{OL(P)}$	Quiet output, maximum dynamic V_{OL}		0.4	0.8	V
$V_{OL(V)}$	Quiet output, minimum dynamic V_{OL}		–0.3	–0.8	V
$V_{OH(V)}$	Quiet output, minimum dynamic V_{OH}		3		V
$V_{IH(D)}$	High-level dynamic input voltage	2.31			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.99	V

(1) Characteristics are for surface-mount packages only.

6.8 Operating Characteristics

$V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	TYP	UNIT
C_{pd}	Power dissipation capacitance	$C_L = 50\text{ pF}$, $f = 10\text{ MHz}$	16	pF

6.9 Typical Characteristics

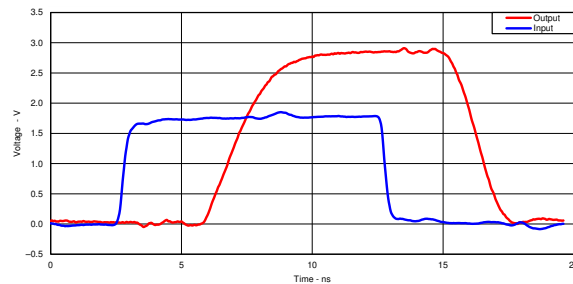
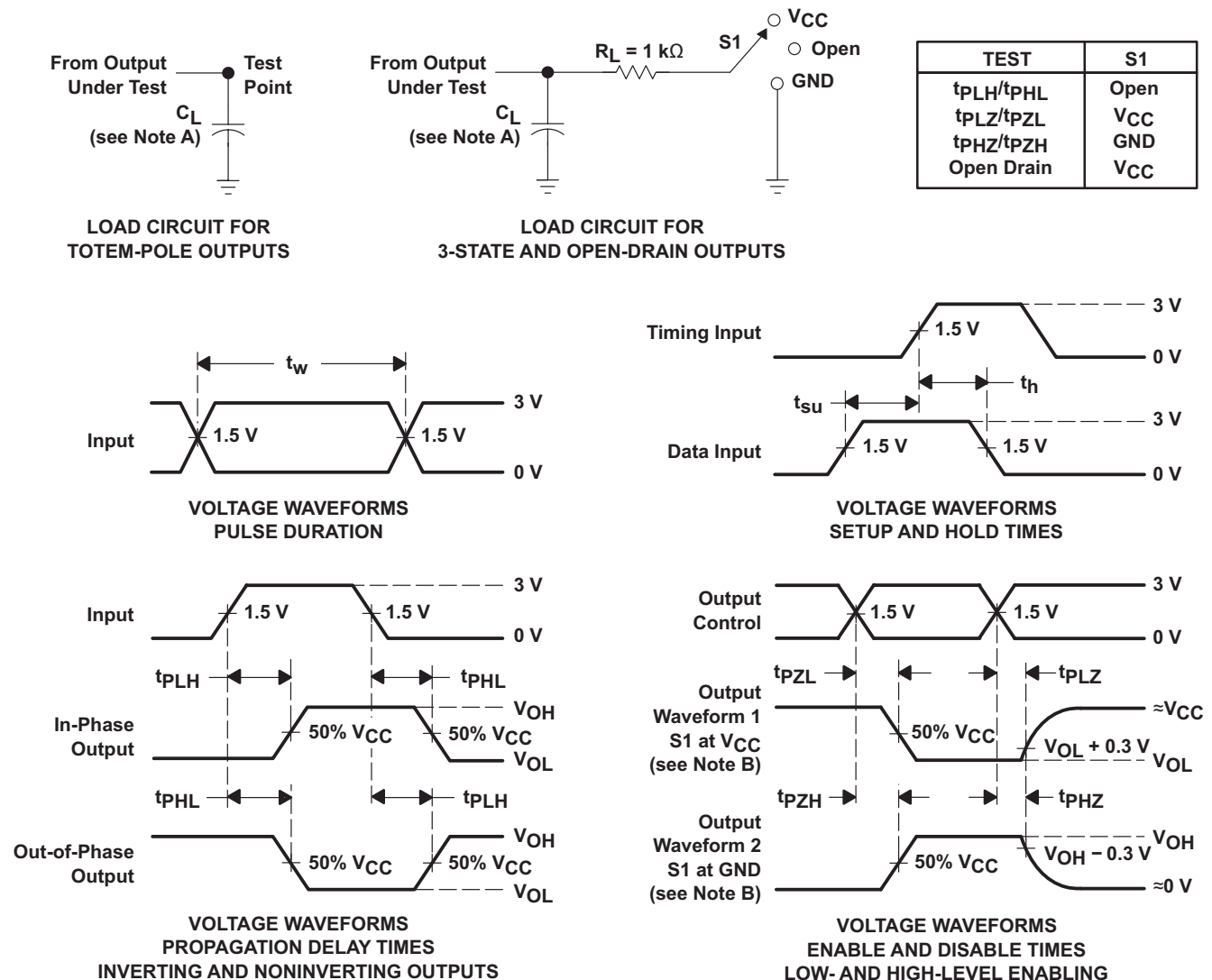


Figure 6-1. Switching Characteristics at 50 MHz
Excellent Signal Integrity (1.8 V to 3.3 V at 3.3-V V_{CC})

7 Parameter Measurement Information

7.1



- NOTES: A. C_L includes probe and jig capacitance.
 B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR $\leq 1\text{ MHz}$, $Z_O = 50\ \Omega$, $t_r \leq 3\text{ ns}$, $t_f \leq 3\text{ ns}$.
 D. The outputs are measured one at a time, with one input transition per measurement.
 E. All parameters and waveforms are not applicable to all devices.

Figure 7-1. Load Circuit and Voltage Waveforms

8 Detailed Description

8.1 Overview

The SN74LVxTxx family was created to allow up- or down-voltage translation with only one power rail. The family has over-voltage tolerant inputs that allow down translation from up to 5.5 V to the V_{CC} level that can be as low as 1.8 V. The family SN74LVxTxx also has a lowered switching threshold that allows it to translate up to the V_{CC} level that can be as high as 5.5 V.

8.1.1 Translating Down

Using these parts to translate down is very simple. Because the inputs are tolerant to 5.5 V at any valid V_{CC} , they can be used to down translate. The input can be any level above V_{CC} up to 5.5 V and the output will equal the V_{CC} level, which can be as low as 1.8 V. One important advantage to down translating using this part is that the I_{CC} current will remain less than or equal to the specified value.

Down translation possibilities with SN74LVxTxx:

- With 1.8-V V_{CC} from 2.5 V, 3.3 V, or 5 V down to 1.8 V.
- With 2.5-V V_{CC} from 3.3 V or 5 V down to 2.5 V.
- With 3.3-V V_{CC} from 5 V down to 3.3 V.

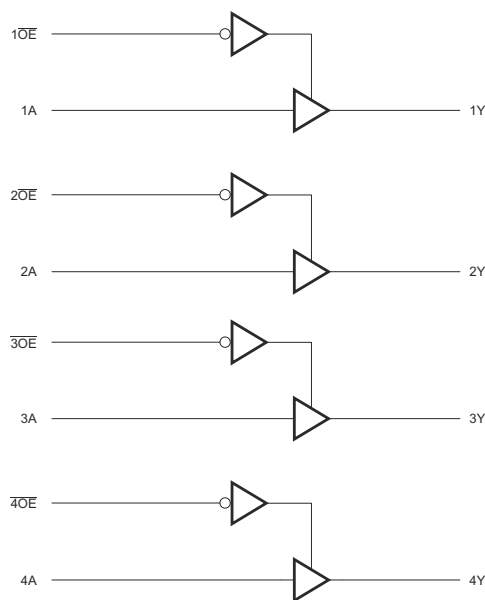
8.1.2 Translating Up

Using the SN74LVxTxx family to translate up is very simple. The input switching threshold is lowered so the high level of the input voltage can be much lower than a typical CMOS V_{IH} . For instance, If the V_{CC} is 3.3 V then the typical CMOS switching threshold would be $V_{CC} / 2$ or 1.65 V. This means the input high level must be at least $V_{CC} \times 0.7$ or 2.31 V. On the LVxT devices the input threshold for 3.3-V V_{CC} is approximately 1 V. This allows a signal with a 1.8-V V_{IH} to be translated up to the V_{CC} level of 3.3 V.

Up translation possibilities with SN74LVxTxx:

- With 2.5-V V_{CC} from 1.8 V to 2.5 V.
- With 3.3-V V_{CC} from 1.8 V or 2.5 V to 3.3 V.
- With 5-V V_{CC} From 2.5 V or 3.3 V to 5 V.

8.2 Functional Block Diagram



8.3 Feature Description

This part is a single supply buffer that is capable up or down translation. The output will equal V_{CC} while the input can vary from 1.2 V to 5.5 V.

Up Translation Mode:

- 1.2 V to 1.8 V at 1.8-V V_{CC}
- 1.5 V to 2.5 V at 2.5-V V_{CC}
- 1.8 V to 3.3 V at 3.3-V V_{CC}
- 3.3 V to 5.0 V at 5.0-V V_{CC}

Down Translation Mode:

- 3.3 V to 1.8 V at 1.8-V V_{CC}
- 3.3 V to 2.5 V at 2.5-V V_{CC}
- 5.0 V to 3.3 V at 3.3-V V_{CC}

8.4 Device Functional Modes

This device performs the function of a buffer where input logic level equals the output logic level, while providing buffering and drive to the output. The SN74LV4T125 device will also translate voltages up or down while performing this function.

**Table 8-1. Function Table
(Each Buffer)**

INPUTS ⁽¹⁾		OUTPUT ⁽²⁾
\overline{OE}	A	Y
L	H	H
L	L	L
H	X	Z

Table 8-2. Supply $V_{CC} = 3.3$ V

INPUT b (Lower Level Input)		OUTPUT (V_{CC} CMOS)
A	B	Y
$V_{IH}(\min) = 1.35$ V		$V_{OH}(\min) = 2.9$ V
$V_{IL}(\max) = 0.8$ V		$V_{OL}(\max) = 0.2$ V

- (1) H = High Voltage Level, L = Low Voltage Level, X = Do not Care, Z = High Impedance
 (2) H = Driving High, L = Driving Low, Z = High Impedance State

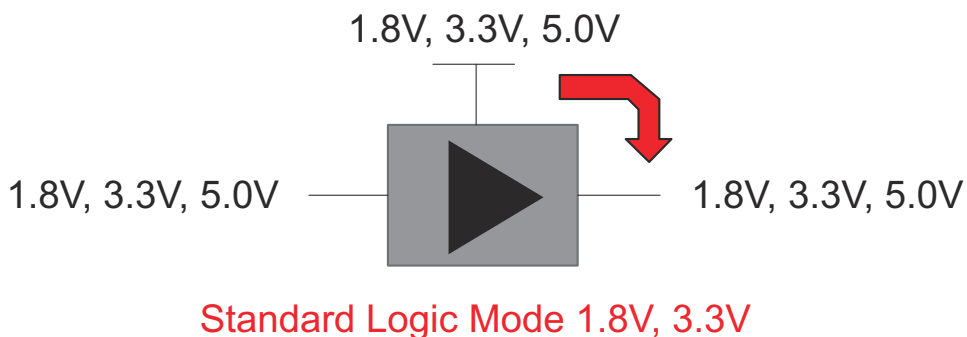
9 Applications and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

Based upon the lower-threshold circuit design of the LVxT family, the LVxT family also supports level translation. For level translation up and down, the LVxT family requires only a single power supply.



9.2 Typical Application

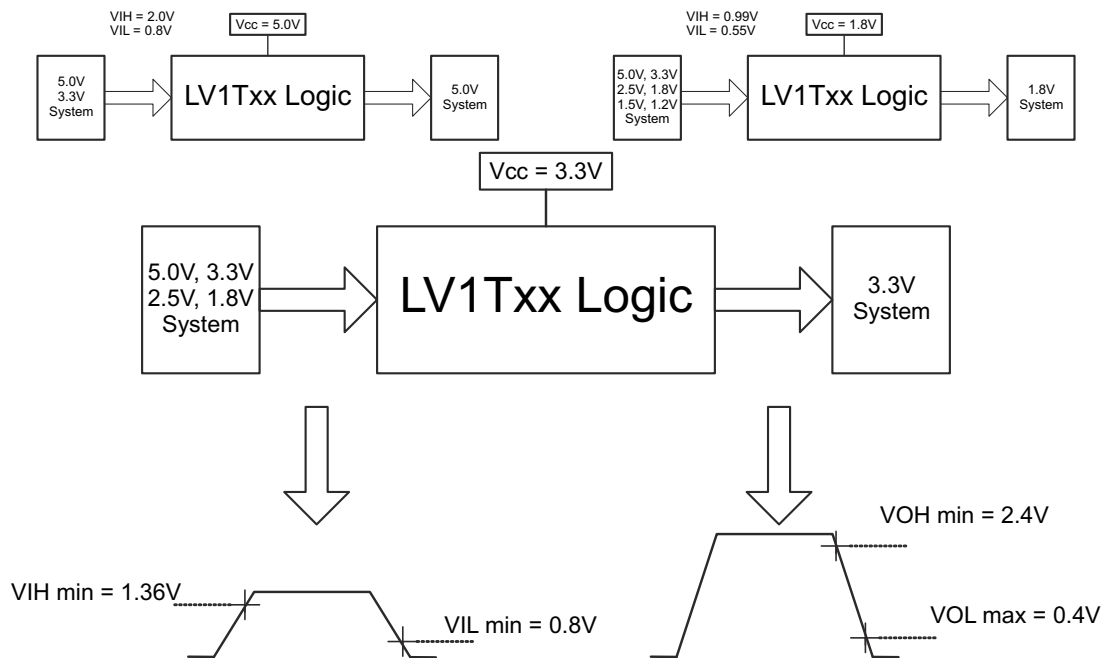


Figure 9-1. Switching Thresholds for 1.8 V to 3.3 V Translation

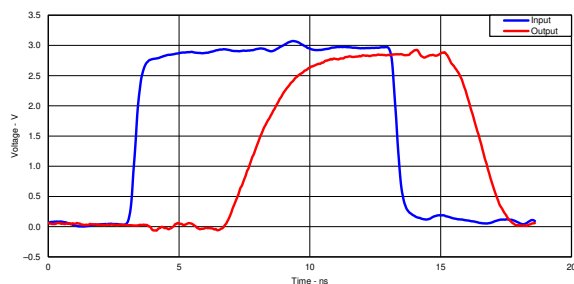
9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. The input threshold levels are lowered to allow for up translation. At 5 V the device has equivalent TTL input levels.

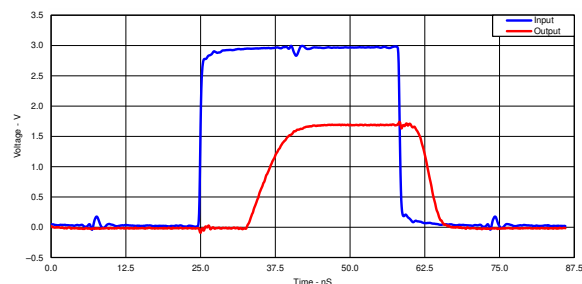
9.2.2 Detailed Design Procedure

1. Recommended input conditions:
 - Rise time and fall time specifications. See ($\Delta t/\Delta V$) in [Recommended Operating Conditions](#) table.
 - Specified high and low levels. See (V_{IH} and V_{IL}) in [Recommended Operating Conditions](#) table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC} .
2. Recommend output conditions:
 - Load currents should not exceed 35 mA per output and 70 mA total for the part.
 - Outputs should not be pulled above V_{CC} .

9.2.3 Application Curves



**Figure 9-2. Switching Characteristics at 50 MHz
Excellent Signal Integrity (3.3 V to 3.3 V at 3.3-V
 V_{CC})**



**Figure 9-3. Switching Characteristics at 15 MHz
Excellent Signal Integrity (3.3 V to 1.8 V at 1.8-V
 V_{CC})**

10 Power Supply Recommendations

The power supply can be any voltage between the Min and Max supply voltage rating located in the [Recommended Operating Conditions](#).

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μF is recommended. If there are multiple V_{CC} pins, then 0.01 μF or 0.022 μF is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μF and 1 μF are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

11 Layout

11.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified in [Figure 11-1](#) are the rules that must be observed under all circumstances.

All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} whichever make more sense or is more convenient.

It is generally acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin it will disable the outputs section of the part when asserted. This will not disable the input section of the IOs so they also cannot float when disabled.

11.2 Layout Example

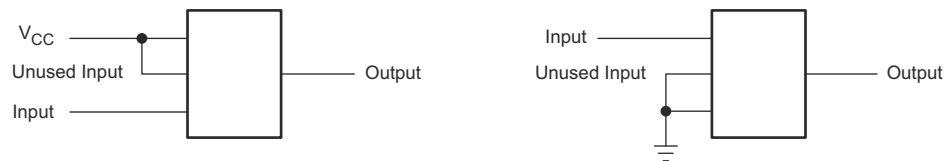


Figure 11-1. Layout Diagram

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Additional Product Selection

DEVICE	PACKAGE	DESCRIPTION
SN74LV1T00	DCK, DBV	2-Input Positive-NAND Gate
SN74LV1T02	DCK, DBV	2-Input Positive-NOR Gate
SN74LV1T04	DCK, DBV	Inverter Gate
SN74LV1T08	DCK, DBV	2-Input Positive-AND Gate
SN74LV1T34	DCK, DBV, DRL	Single Buffer Gate
SN74LV1T14	DCK, DBV	Single Schmitt-Trigger Inverter Gate
SN74LV1T32	DCK, DBV	2-Input Positive-OR Gate
SN74LV1T86	DCK, DBV	Single 2-Input Exclusive-Or Gate
SN74LV1T125	DCK, DBV, DRL	Single Buffer Gate with 3-state Output
SN74LV1T126	DCK, DBV, DRL	Single Buffer Gate with 3-state Output
SN74LV4T125	RGY, PW	Quadruple Bus Buffer Gate With 3-State Outputs

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

12.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74LV4T125PWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LV4T125
SN74LV4T125PWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV4T125
SN74LV4T125PWR.B	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	-	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV4T125
SN74LV4T125RGYR	Active	Production	VQFN (RGY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVT125
SN74LV4T125RGYR.A	Active	Production	VQFN (RGY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVT125
SN74LV4T125RGYRG4	Active	Production	VQFN (RGY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVT125
SN74LV4T125RGYRG4.A	Active	Production	VQFN (RGY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVT125

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF SN74LV4T125 :

- Automotive : [SN74LV4T125-Q1](#)
- Enhanced Product : [SN74LV4T125-EP](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV4T125PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV4T125PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV4T125RGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1
SN74LV4T125RGYRG4	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

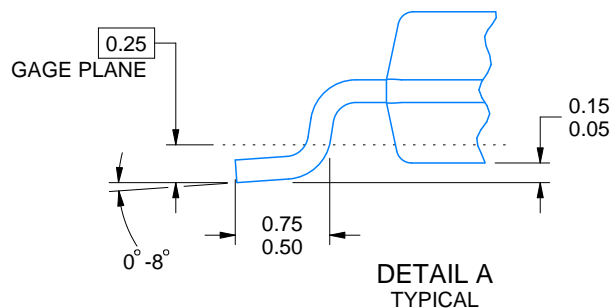
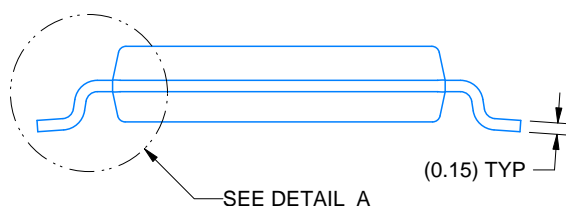
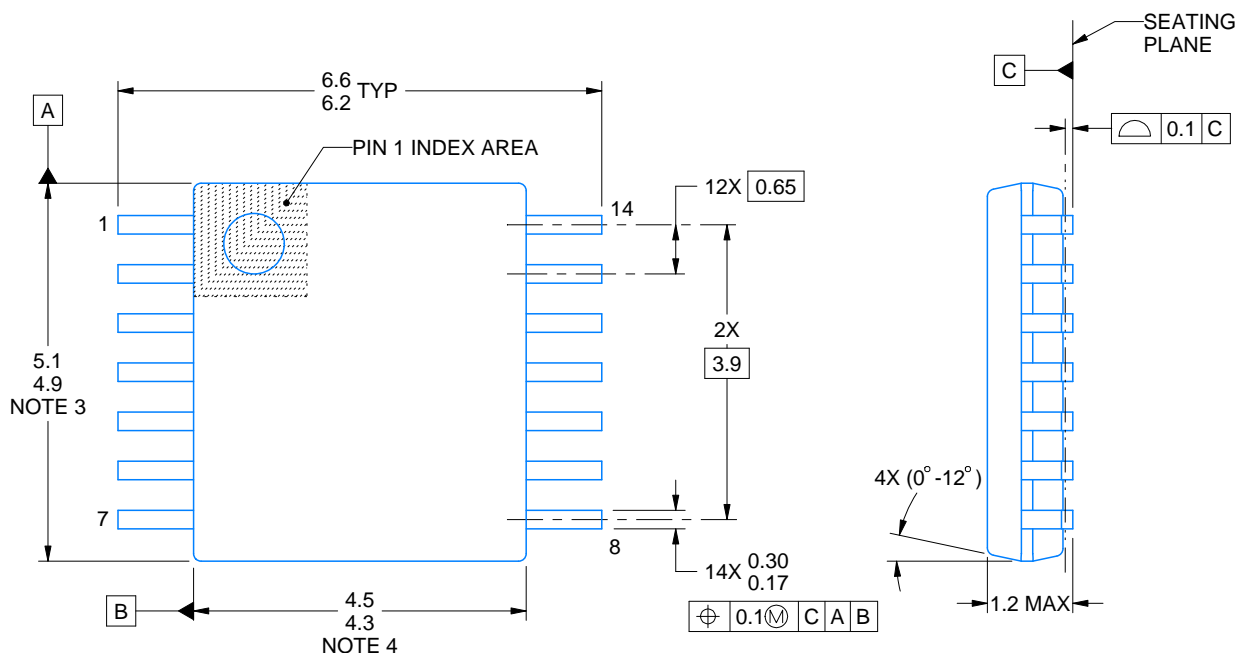
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV4T125PWR	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74LV4T125PWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV4T125RGYR	VQFN	RGY	14	3000	360.0	360.0	36.0
SN74LV4T125RGYRG4	VQFN	RGY	14	3000	360.0	360.0	36.0



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



4220202/B 12/2023

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220202/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

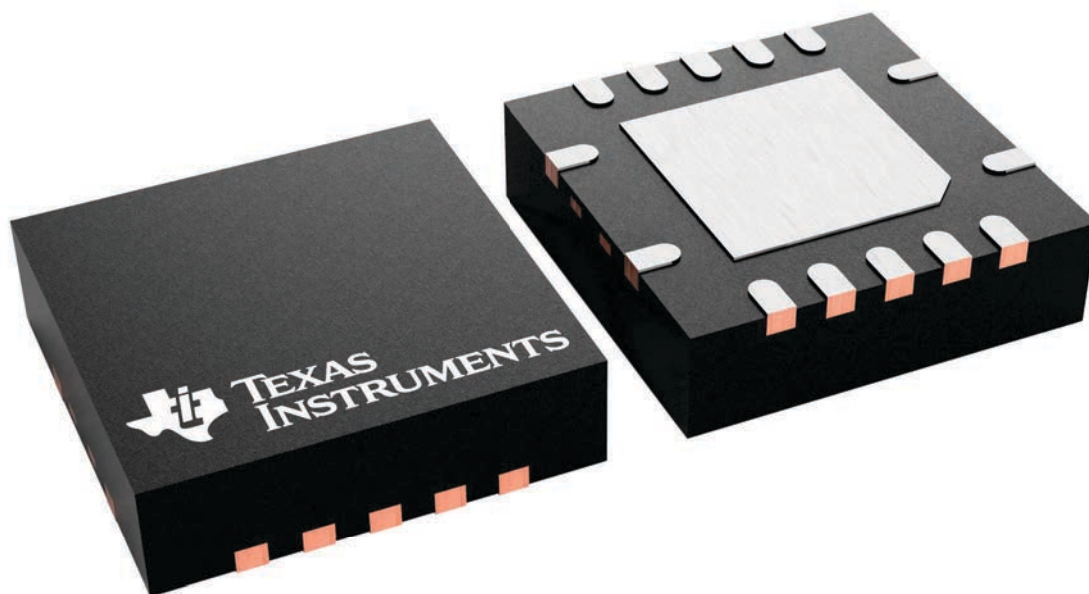
RGY 14

VQFN - 1 mm max height

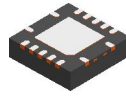
3.5 x 3.5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



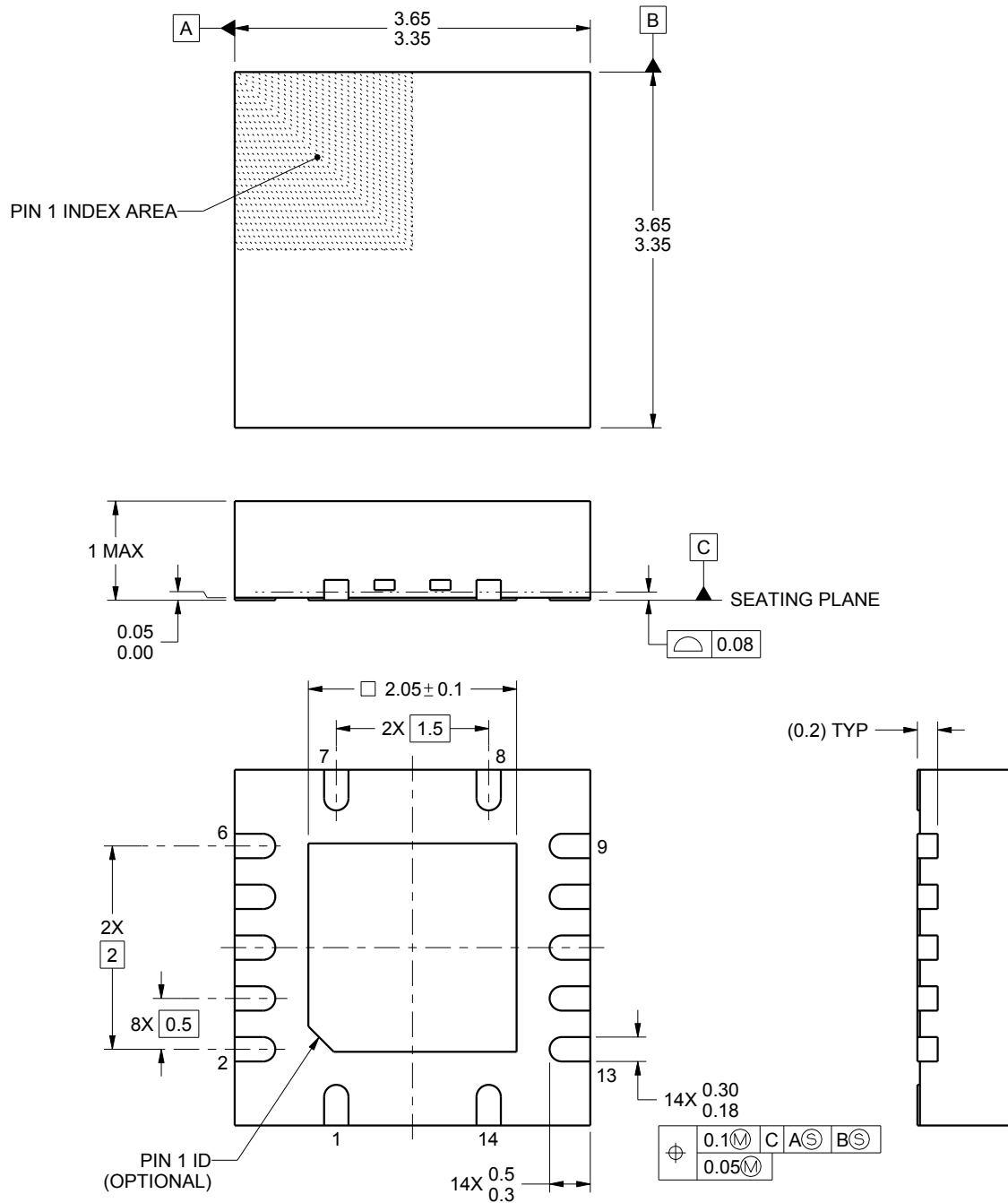
RGY0014A



PACKAGE OUTLINE

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



4219040/A 09/2015

NOTES:

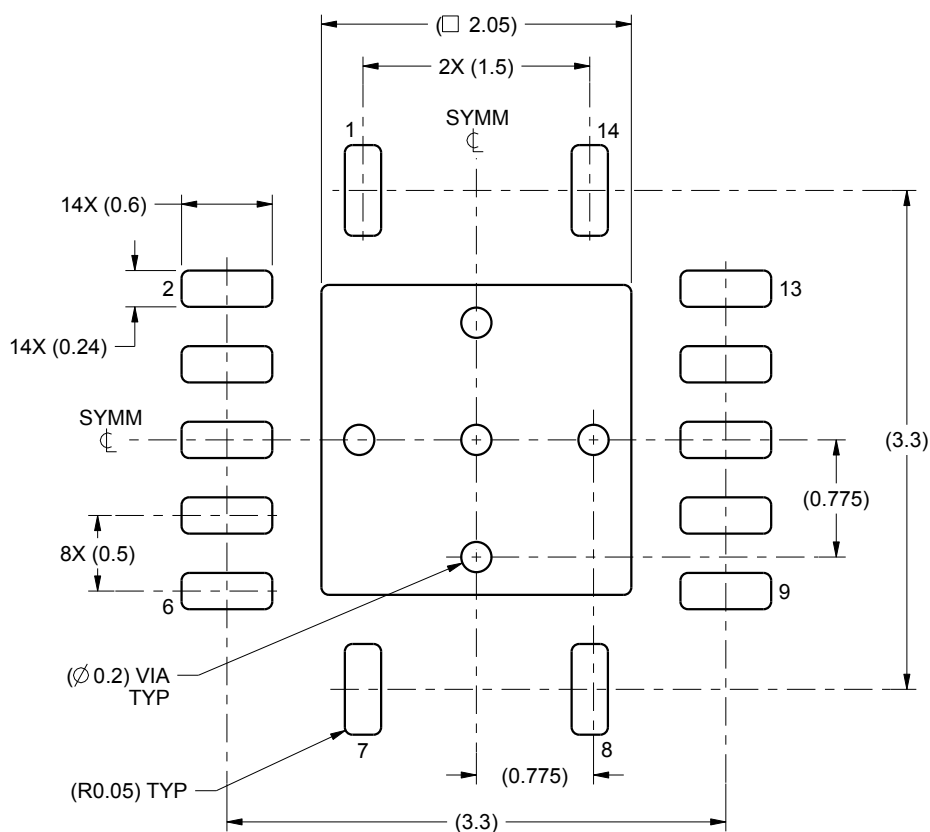
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

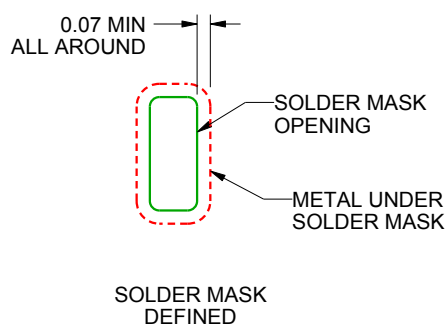
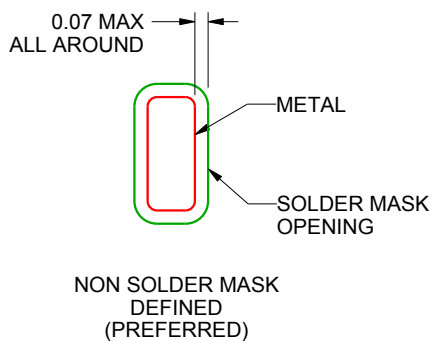
RGY0014A

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
SCALE:20X



SOLDER MASK DETAILS

4219040/A 09/2015

NOTES: (continued)

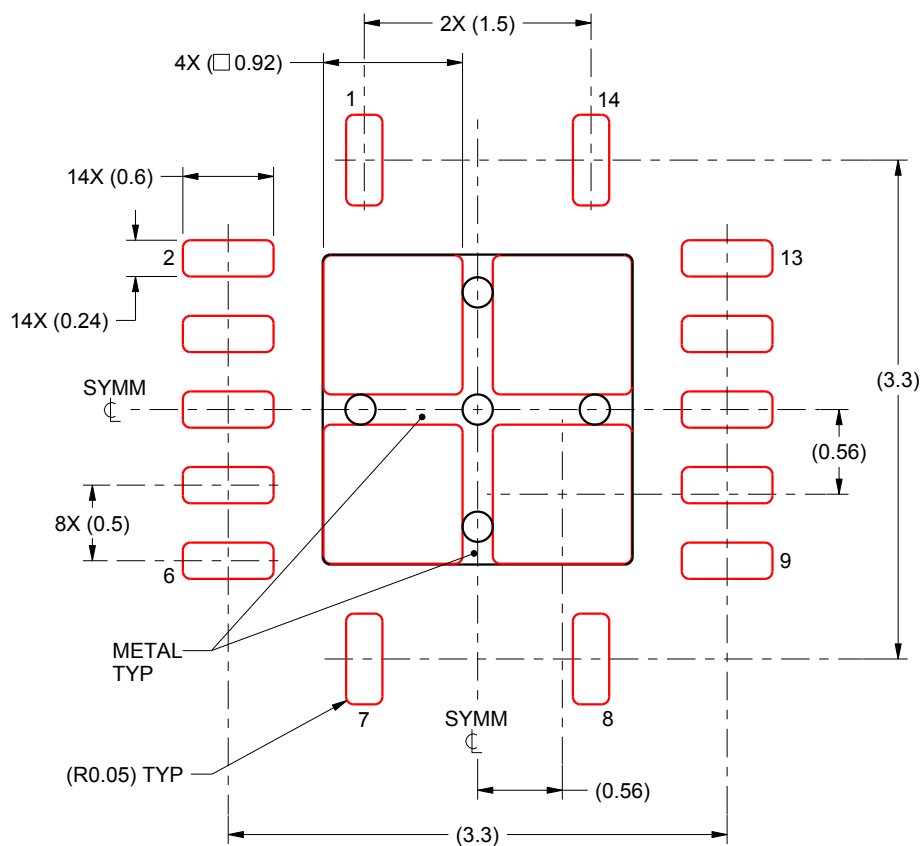
- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slue271).

EXAMPLE STENCIL DESIGN

RGY0014A

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
80% PRINTED SOLDER COVERAGE BY AREA
SCALE:20X

4219040/A 09/2015

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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